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UNIVERSITY OF UTAH
ELECTRICAL AND COMPUTER ENGINEERING DEPARTMENT

MICROWAVE ENGINEERING I

ECE 5320/6322

MIDTERM EXAMINATION NO. 2

November 7, 2008

1. (25 points)

Pts

9 a. Write the ABCD parameters of the following circuit:

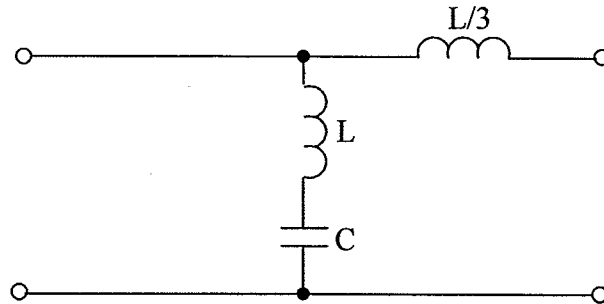


Fig. 1

8 b. Show that $AD - BC = 1$ for this circuit.

8 c. If $L = 3 \text{ nH}$, calculate the value of C to get a shunt arm resonant frequency of 3 GHz .

- ABCD parameters for the
 1. a. From the first two elements in Table 4.1 p. 185 of the Text

$$\begin{bmatrix} A & B \\ C & D \end{bmatrix} = \begin{bmatrix} 1 & 0 \\ \frac{1}{j(\omega L - \frac{1}{\omega C})} & 1 \end{bmatrix} \begin{bmatrix} 1 & j\frac{\omega L}{3} \\ 0 & 1 \end{bmatrix}$$

$$= \begin{bmatrix} 1 & \frac{j\omega L}{3} \\ \frac{1}{j(\omega L - \frac{1}{\omega C})} & \frac{j\omega L}{3} \frac{1}{j(\omega L - \frac{1}{\omega C})} + 1 \end{bmatrix}$$

b. $AD - BC = \left[1 + \frac{\cancel{\omega L}}{(\omega L - \frac{1}{\omega C})} \right] - \frac{\cancel{j\omega L}}{j(\omega L - \frac{1}{\omega C})} = 1$

- c. For the shunt branch, the resonant frequency is given by the equation

$$\omega_r L - \frac{1}{\omega_r C} = 0 \rightarrow \omega_r = \sqrt{\frac{1}{LC}}$$

$$f_r = 3 \text{ GHz} = \sqrt{\frac{1}{LC}} \cdot \frac{1}{2\pi}$$

$$\frac{1}{LC} = (2\pi \times 3 \times 10^9)^2$$

$$C = \frac{1}{\cancel{(3 \times 10^9)} (2\pi)^2 \times 9 \times 10^{18}} = \boxed{0.938 \text{ pF}}$$

2. (25 points)

The layout of a single section coupled **microstripline** directional coupler using alumina ($\epsilon_r = 10$) as the substrate is as shown in Fig. 2. Assuming that the thickness d of the substrate is $1/16$ ":

Pts

- 12 a. Calculate the length ℓ , width W , and spacing S in **millimeters** for a $Z_0 = 60\Omega$ coupler with a coupling factor of -13.0 dB for a center frequency of 3 GHz ($\theta = 90^\circ$ for the coupled section).
- 13 b. Calculate the angles θ and the corresponding upper and lower frequencies for which the coupling factor is -14.0 dB.

Hint: From Eq. 7.88a

$$\frac{V_3}{V_1} = jc \sin \theta e^{-j\theta}$$

$$\text{Coupling factor } C = 20 \log c = -13 \text{ dB}$$

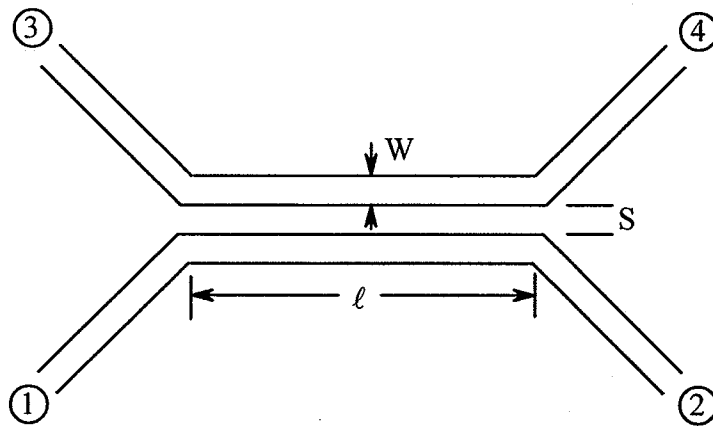


Fig. 2.

$$2. a. \quad C = -13 \text{ dB} = 20 \log c \rightarrow c = 10^{-13/20} = 0.2239$$

From Eqs. 7.87 a, b

$$Z_{oe} = Z_0 \sqrt{\frac{1+c}{1-c}} = 75.39 \Omega$$

$$Z_{oo} = Z_0 \sqrt{\frac{1-c}{1+c}} = 47.75 \Omega$$

From Fig. 7.32 (for the microstrip coupler with $\epsilon_r = 10$)

$$\frac{S}{d} \approx 0.6 ; \quad \frac{W}{d} \approx 0.6$$

It is given that $d = \frac{1}{16}'' = 1.5875 \text{ mm}$

$$S = 0.953 \text{ mm} ; \quad W = 0.953$$

$$\lambda_0 = 10 \text{ cm} = 100 \text{ mm}$$

$$\text{For } \theta = 90^\circ \quad l = \lambda_g / 4 = \frac{100}{4\sqrt{\epsilon_{eff}}} \text{ mm}$$

Possibility 1

Since ϵ_{eff} is not prescribed, we can assume $\epsilon_{eff} = \epsilon_r = 10$

$$\text{in this case } l = \frac{\lambda_g}{4} = \frac{25}{\sqrt{10}} = 7.9 \text{ mm}$$

Possibility 2

A more accurate procedure is to calculate ϵ_{eff} from Eq. 3.195 on p. 144 for the effective dielectric constant of a microstrip line for $W/d \approx 0.6$ obtained above

$$\epsilon_{eff} = \frac{\epsilon_r + 1}{2} + \frac{\epsilon_r - 1}{2} \frac{1}{\sqrt{12 \frac{d}{W} + 1}} \quad (3.195)$$

$$\text{From this Eq. we get } \epsilon_{eff} = 6.48$$

$$\text{Therefore } l = \frac{\lambda_g}{4} = \frac{100}{4\sqrt{6.48}} = 9.82 \text{ mm (This is more accurate!)}$$

b. For a coupling factor $C = -14 \text{ dB}$, we get $c' = 10^{-14/20} = 0.1995$

$$c' = c \sin \theta = 0.1995$$

$$\sin \theta = \frac{0.1995}{0.2239} = 0.8911$$

$$\theta_1 = 63^\circ ; \quad \theta_2 = 180 - 63 = 117^\circ \quad \leftarrow \frac{W}{d}$$

$$f_{\text{lower}} = \frac{63}{90} \times 3 = 2.1 \text{ GHz} ; \quad f_{\text{higher}} = \frac{117}{90} = 3.9 \text{ GHz}$$

3. (25 points)

Pts

- 15 a. Design a bisected or half π -section m-derived low-pass filter with the following specifications:

$$R_o = 60\Omega$$

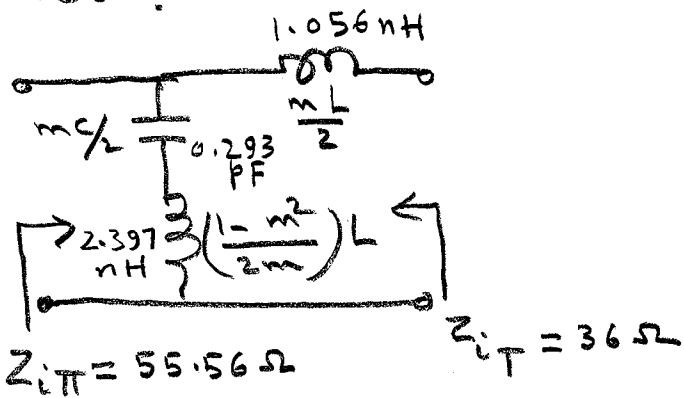
$$f_c = 5 \text{ GHz}$$

$$f_\infty = 6 \text{ GHz}$$

Calculate the values of shunt elements (L, C) and series inductance to use for this half-section filter.

- 10 b Calculate and mark the image impedances Z_T and Z_π for your half section m-derived filter for a signal frequency of 4 GHz.

3. a. From the bottom part of Table 8.2 p. 387 of the Text, the bisected (half section) π -section low pass filter circuit is as shown below:



From Eqs. (8.37) and (8.38) [see also the eqs. on p. 8-4 of my Notes]

$$L = \frac{2R_0}{\omega_c} = \frac{R_0}{\pi f_c} = \frac{60}{\pi \times 5 \times 10^8} = 3.82 \text{ nH}$$

$$C = \frac{2}{\omega_c R_0} = \frac{1}{\pi f_c R_0} = \frac{1}{\pi \times 5 \times 10^8 \times 60} = 1.061 \text{ pF}$$

From Eq. 8.44 of the Text

$$f_{\infty} = \frac{f_c}{\sqrt{1-m^2}} \Rightarrow 1-m^2 = \left(\frac{f_c}{f_{\infty}}\right)^2 = \left(\frac{5}{6}\right)^2 = 0.694$$

$$m = \sqrt{1 - \left(\frac{f_c}{f_{\infty}}\right)^2} = 0.553$$

For the shunt branch of the above bisected π -section ckt.

$$\frac{mC}{2} = 0.293 \text{ pF} ; \left(\frac{1-m^2}{2m}\right)L = 2.397 \text{ nH}$$

For the series branch

$$\frac{mL}{2} = 1.056 \text{ nH}$$

b. From Eq. (8.35) of the Text

$$Z_{Tm} = Z_{Tk} = R_0 \sqrt{1 - \frac{\omega^2}{\omega_c^2}} = 60 \sqrt{1 - \left(\frac{4}{5}\right)^2} = 36 \Omega$$

From Eq. 8.46 of the Text

$$Z_{i\pi} = \frac{1 - (1-m^2)\left(\frac{\omega}{\omega_c}\right)^2}{\sqrt{1 - \left(\frac{\omega}{\omega_c}\right)^2}} R_0 = \frac{1 - \left(\frac{f^2}{f_{\infty}^2}\right)}{\sqrt{1 - \left(\frac{f^2}{f_c^2}\right)}} R_0$$

$$= \frac{1 - \left(\frac{4}{6}\right)^2}{\sqrt{1 - \left(\frac{4}{5}\right)^2}} \cdot 60 = 55.56 \Omega$$

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Score:

Problem 1 _____ of a possible 25 points

Problem 2 _____ of a possible 25 points

Problem 3 _____ of a possible 25 points

Total _____ of a possible 75 points